Application Number 10/814,046 Amendment dated December 15, 2004 Responsive to Office Action mailed October 18, 2004

LISTING OF CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application.

Listing of Claims:

Claim 1 (Currently Amended):

An apparatus comprising:

a class E amplifier having a first transistor;

a second transistor controlling a current path in parallel to the first transistor, and further wherein the second transistor has a source connected to ground and a drain connected to a drain of the first transistor by a resistor; and

a controller to control the first and second transistors.

The apparatus of claim 1, wherein the first and second Claim 2 (Currently Amended): transistors comprise metal oxide semi conductor field-effect transistors (MOSFET's), and furtherwherein the second transistor has a so pree connected to ground and a drain connected to a drainof the first transistor by a resistor.

The apparatus of claim 1, wherein the apparatus produces and amplitude Claim 3 (Original): modulated signal in response to the controller by:

for a first period of time, simultaneously switching the first transistor to a frequency and deactivating the second transistor; and

for a second period of time, simultaneously deactivating the first transistor and activating the second transistor.

Claim 4 (Original): The apparatus ϕ f claim 3, wherein the frequency is at least 13.56 megahertz.

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The apparatus of claim 1, wherein the class E amplifier includes an Claim 5 (Original): inductor supply current to the first tradsistor, and a shunt capacitor connected in parallel to the first transistor.

Claim 6 (Original): An amplifier comprising:

a first transistor;

an inductor coupling the first tansistor to a supply voltage via a first resistor;

a shunt capacitor connected in parallel to the first transistor;

a second transistor connected to the inductor by a second resistor, wherein the second transistor controls a current path in parallel to the first transistor and the capacitor;

a third transistor connected in parallel to the first resistor, and

a controller coupled to the first, second and third transistors.

Claim 7 (Original): The amplifier of claim 6, wherein the controller selectively activates the first and second transistors.

Claim 8 (Original): The amplifier of claim 6, wherein the controller activates and deactivates the first transistor at a frequency, and activates and deactivates the second transistor.

Claim 9 (Original): The amplifier of claim 8, wherein the frequency is at least 13.56 megahertz.

Claim 10 (Original): The amplifier of claim 6, wherein the controller activates and deactivates the first transistor at a frequency, and activates and deactivates the third transistor.

Claim 11 (Original): The amplifier of claim 10, wherein the frequency is at least 13.56 megahertz.

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Claim 12 (Original): An apparatus comprising:

a class E amplifier having a first transistor and an inductor coupling the first transistor to a supply voltage via a first resistor;

a second transistor connected in parallel to the first resistor, and a controller coupled to the first and second transistors.

Claim 13 (Original): The apparatus of claim 12, wherein the controller activates and deactivates the first transistor at a frequency, and activates and deactivates the second transistor.

Claim 14 (Original): The apparatus of claim 13, wherein the frequency is at least 13.56 megahertz.

Claim 15 (Original): The apparatus of claim 12, wherein the amplifier further comprises:

a shunt capacitor connected in parallel to the first transistor; and

a third transistor controlling a current path in parallel to the first transistor and the capacitor.

Claim 16 (Original): The apparatus of claim 15, wherein the controller selectively activates the first and third transistors.